Qianshu Wu

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/10069175/publications.pdf

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5	9	3311381 1	2917675
papers	citations	h-index	g-index
5	5	5	5
all docs	docs citations	times ranked	citing authors

#	Article	IF	CITATIONS
1	Threshold Voltage Engineering in Al ₂ O ₃ /AlGaN/GaN MISHEMTs with Thin Barrier Layer: MIS-gate Charge Control and High Threshold Voltage Achievement., 2021,,.		4
2	Charge Control in Schottky-Type p-GaN Gate HEMTs With Partially and Fully Depleted p-GaN Conditions. IEEE Transactions on Electron Devices, 2022, 69, 2262-2269.	3.0	3
3	Influence of the Groove Depth on the Electrical Characteristics of the Vertical GaN Trench MOSFETs., 2020, , .		1
4	Numerical analysis of the GaN trench MIS barrier Schottky diodes with high dielectric reliability and surge current capability. AIP Advances, 2022, 12 , .	1.3	1
5	Mechanism of high conduction on the N polar face of GaN. Journal of Applied Physics, 2022, 131, 235701.	2.5	0